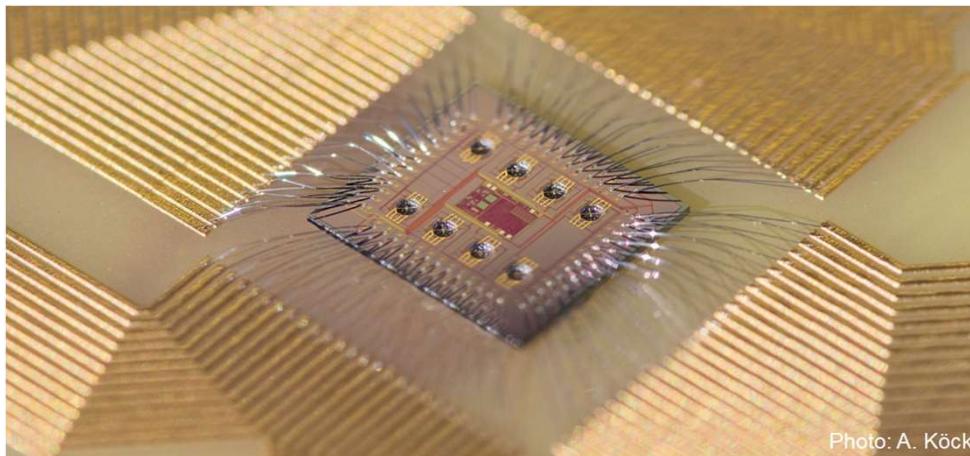


Materials-related challenges for autonomous sensor nodes



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Outline



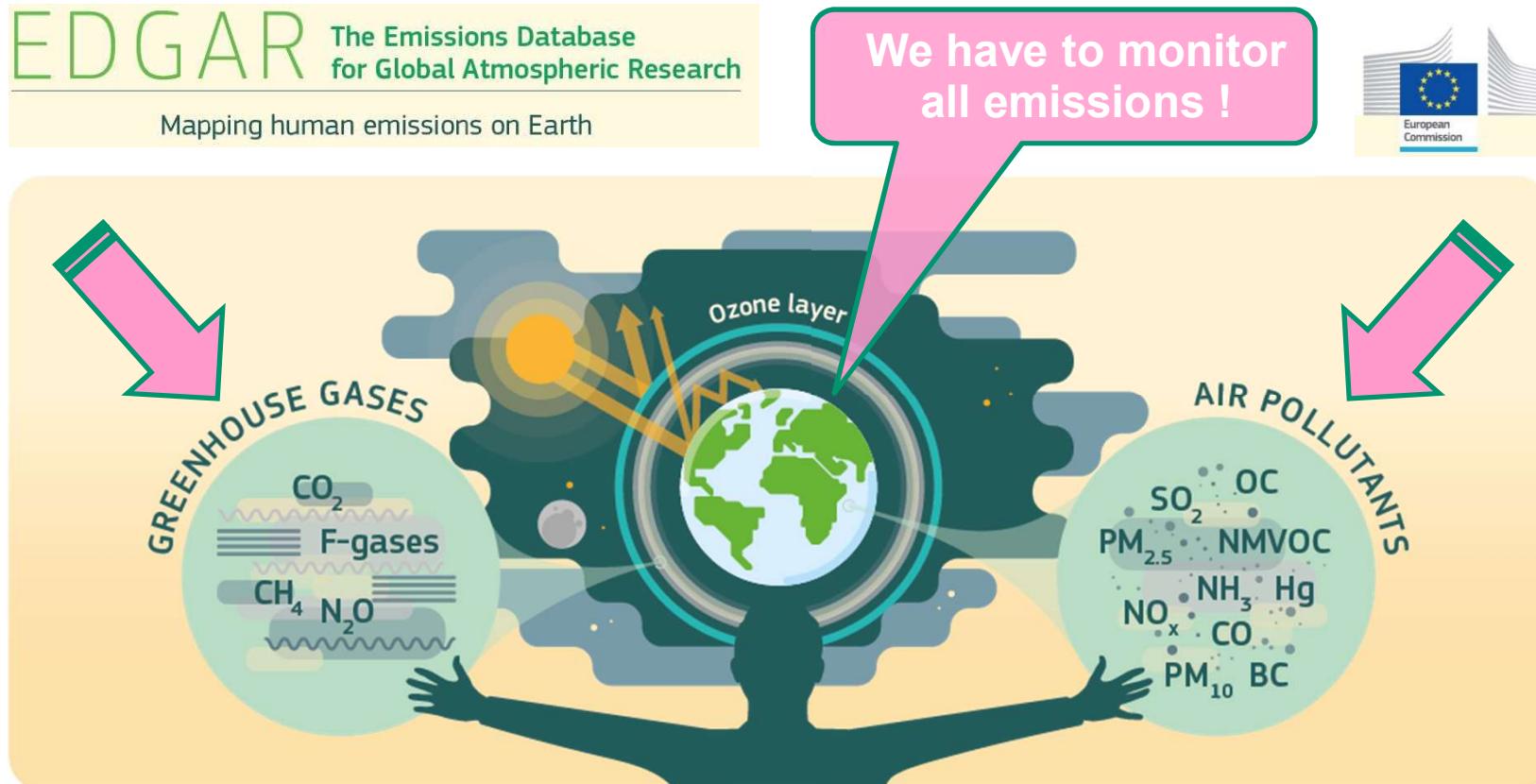
- Wireless Sensor Networks for the Internet of Things (IoT)
- Autonomous sensor nodes
- Strategies to realise energy autonomy
 - Low-power gas sensors
 - Broadband piezoelectric harvesters
 - High-energy density dielectric capacitors
- Integration possibilities

Some definitions...

Digitalisation	converting information to a digital format and making it available	improving business procedures (<i>digital revolution</i>)
https://workingmouse.com.au https://en.wikipedia.org		
Internet-of-Things (IoT)	network of physical devices that enables them to connect and exchange data	realising intelligent (smart) operation
Smart home		Sensors
Smart cities		Actuators
Smart vehicle		CPU
Smart industry (Industry 4.0)		Network
		Power supply
Smart device or system	system capable of analysing the environment and performing intelligent action on the environment.	



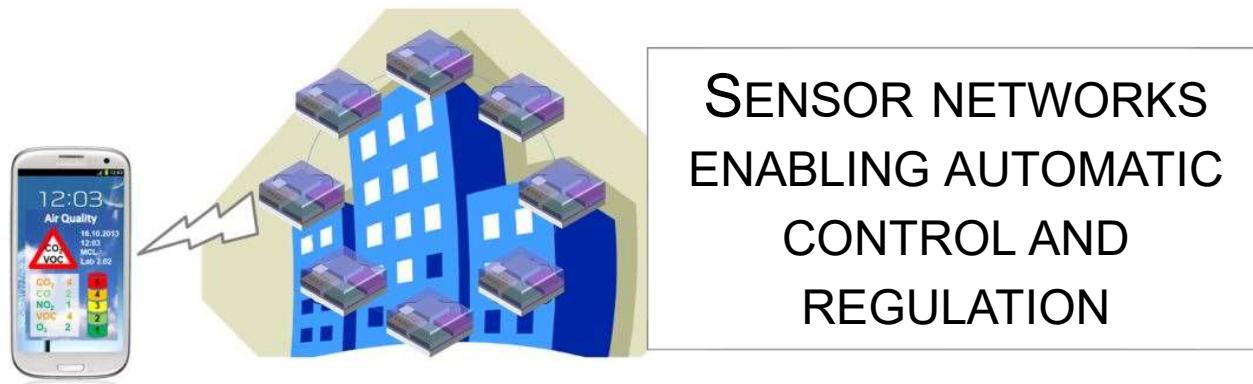
Environmental monitoring



Source: The Emissions Database for Global Atmospheric Research (EDGAR):
<http://edgar.jrc.ec.europa.eu>

Environmental monitoring

Indoor and outdoor air quality monitoring



Wireless Sensor Networks



Air quality monitoring



Condition monitoring



Industry 4.0



Structural health monitoring



Predictive maintenance

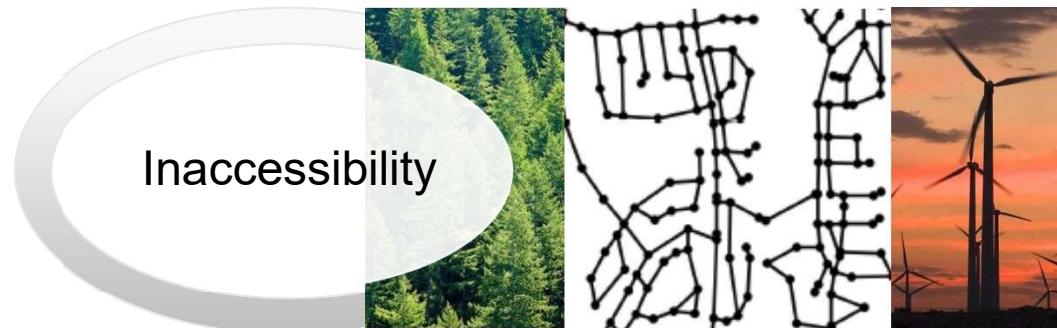
Challenges for sensor networks



Autoevolution.com

DatSciAwards.com

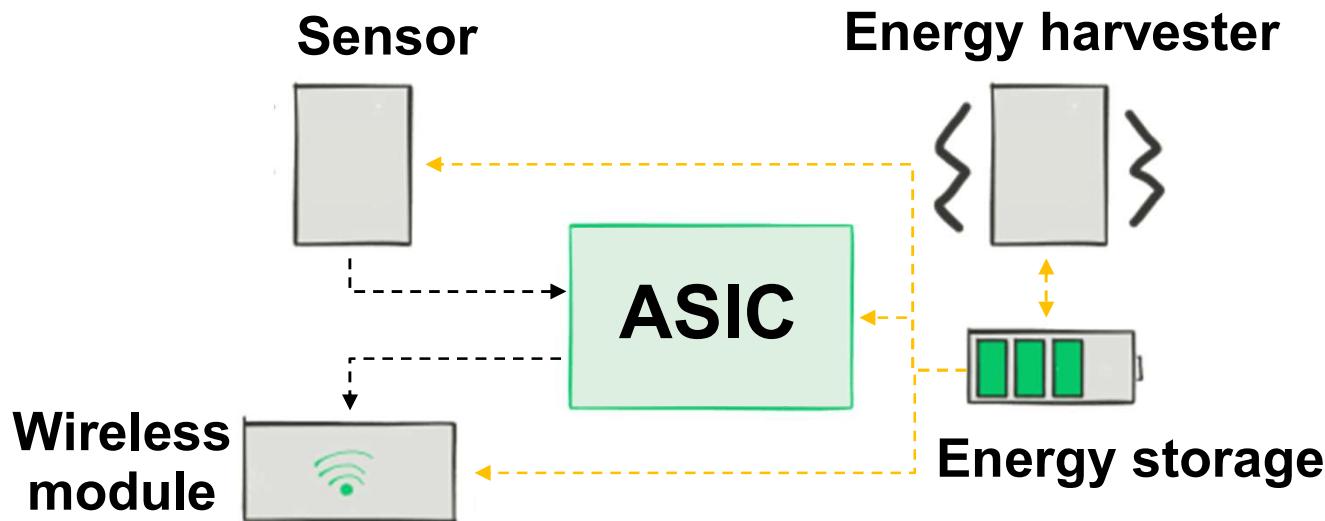
Miniaturisation



 Device footprint  Energy efficiency

Miniaturised self-powered (energy autonomous) sensor nodes

Self-powered wireless sensor nodes



ENERGY CONSUMPTION	CMOS gas sensor: 144 J/d	Temperature sensor: 0.47 J/d
	Self-heating gas sensor: 0.14 J/d	Vibration sensor: 0.6 J/d
	ASIC/RFID (1 read/minute, ≤ 10 m transmission distance): < 0.1 J/d	
ENERGY GENERATION	Photovoltaic harvester: 2.9 kJ/d	Thermoelectric harvester: 5.2 J/d
	Piezoelectric vibration harvester: ~0.9 J/d	
ENERGY STORAGE	Ceramic multilayer capacitor: 2.5×10^{-4} J/cycle	Supercapacitor: 2×10^{-2} J/cycle
	Thin film multilayer capacitor: 2.5×10^{-2} J/cycle	

Materials-related challenges



Low power consumption

- *sensor/harvester performance*

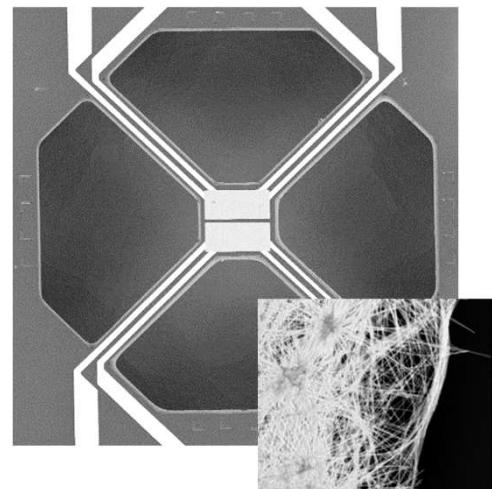
Variability of the energy source

- *harvester + storage unit perf.*

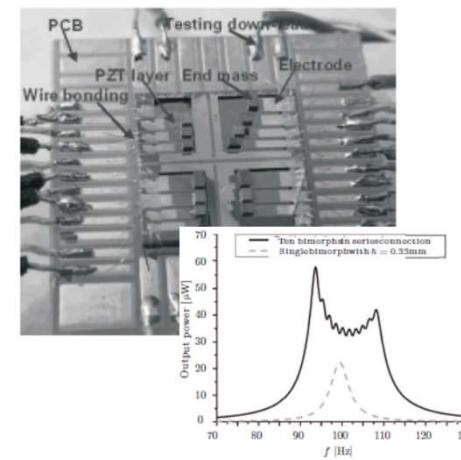
Low cost per unit

- *high-yield low-cost production*

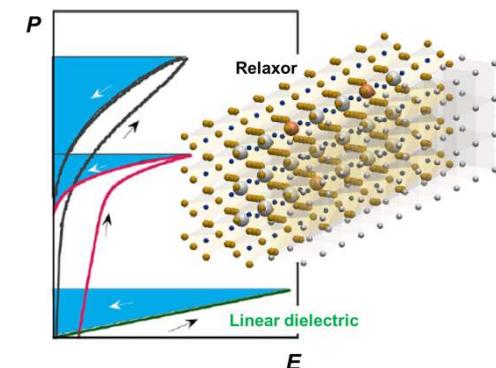
Low-power gas sensors



Broadband piezo-harvesters

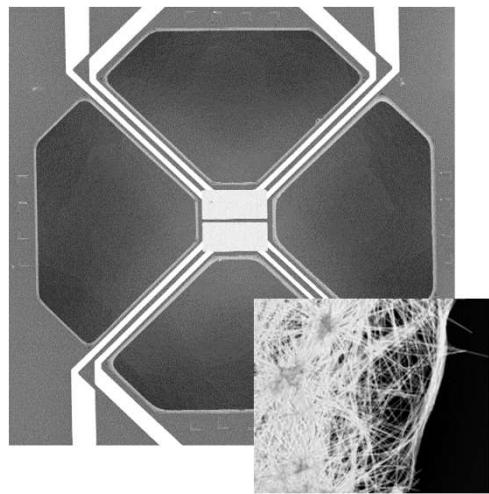


High energy-density capacitors

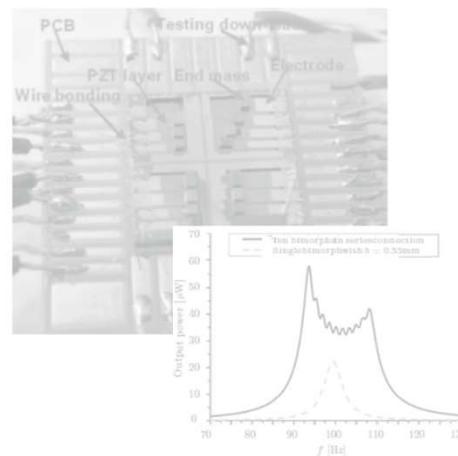




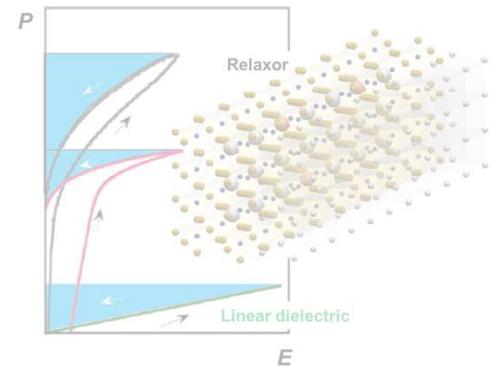
Low-power gas sensors



Broadband piezo-harvesters



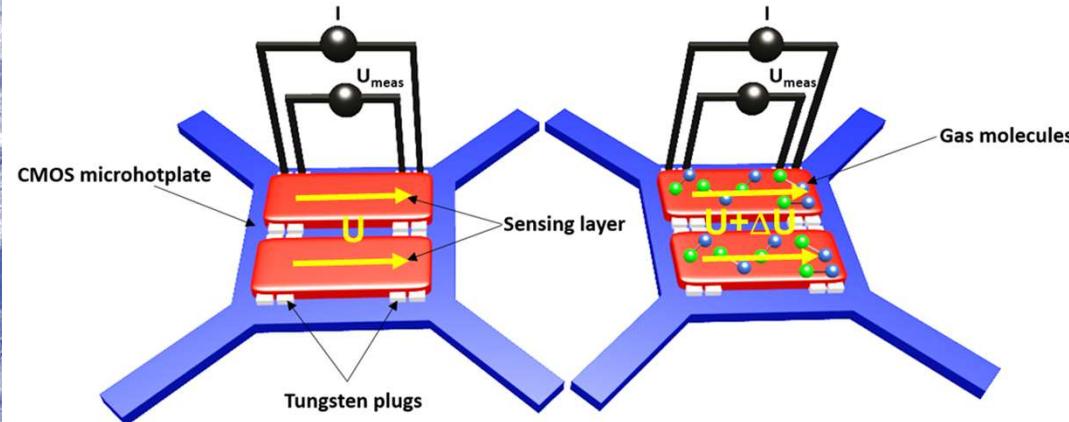
High energy-density capacitors



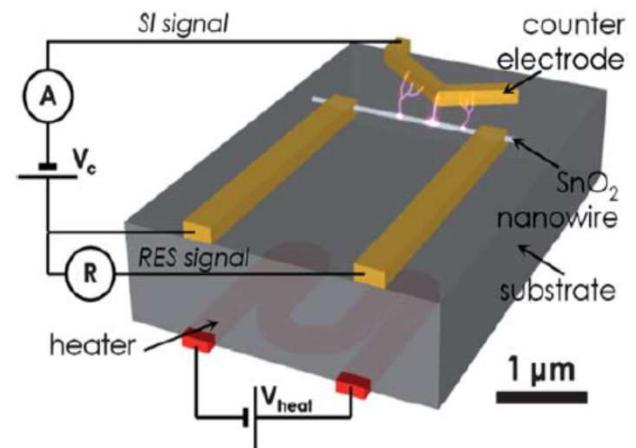
Metal oxide gas sensors



Conductometric (resistive)



Surface ionisation



Sensing Material

- SnO_2
- CuO
- ZnO
- WO_3

Thin films
Nanowires

Functionalising Nanoparticles

- Au, Pt, Pd
- AuPd, PdPt, ...
- ZrO_2
- BaTiO_3

Target Gases

- | | |
|------------------------|----------------------------|
| ■ CO | ■ CO_2 |
| ■ VOCs | ■ NO_2 |
| ■ H_2S | ■ H_2, O_3 |

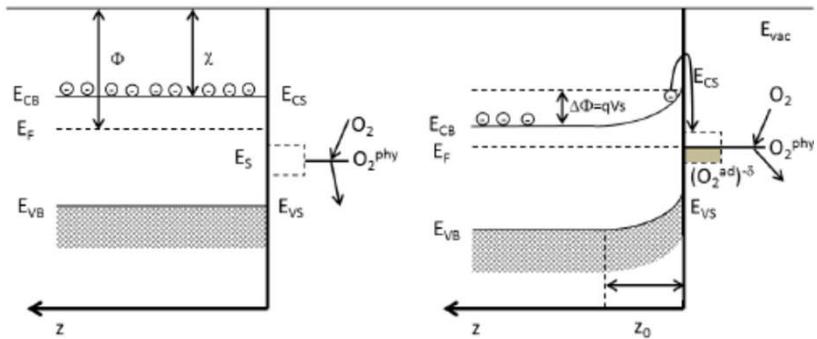
Dry and humid air



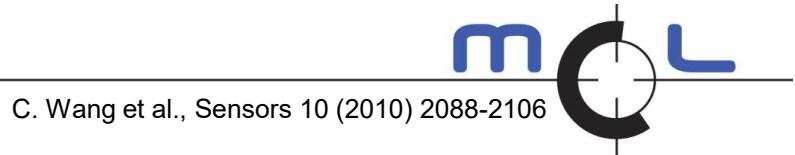
Metal oxide gas sensors

Conductometric Gas Sensor

n-type



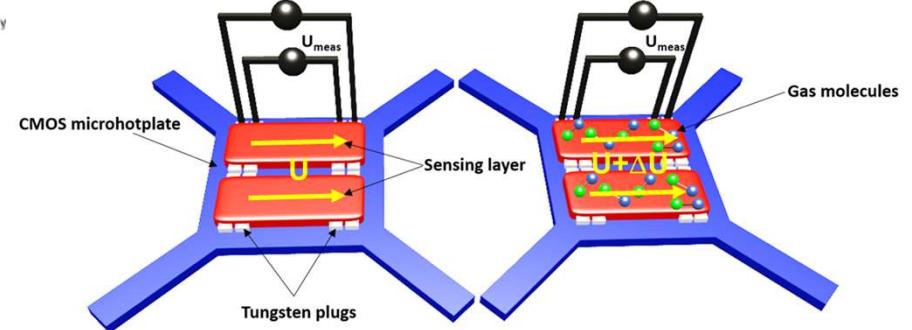
W. Göpel, Prog. Surf. Sci 20 (1985) 9-103



C. Wang et al., Sensors 10 (2010) 2088-2106



Reaction of gas with adsorbed O⁻ changes the resistance of the



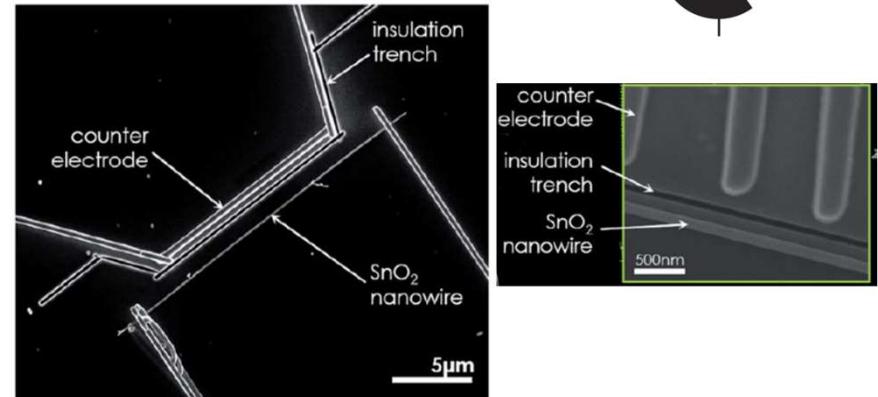
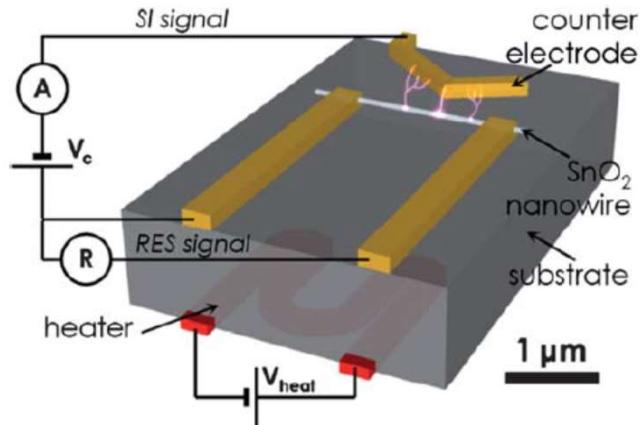
- Optimal reaction T: 300° C – 450° C → Hotplate needed
- Decreasing particle size, surface/volume ratio of sensing surface layer increases
 - Nanocrystalline thin films and nanowires ↑ Sensitivity
- Doping with noble metal particles is beneficial
 - Catalyses the reaction with gas ↑ Sensitivity
 - Improves electron exchange in sensing layer ↑ Sensitivity

Metal oxide gas sensors

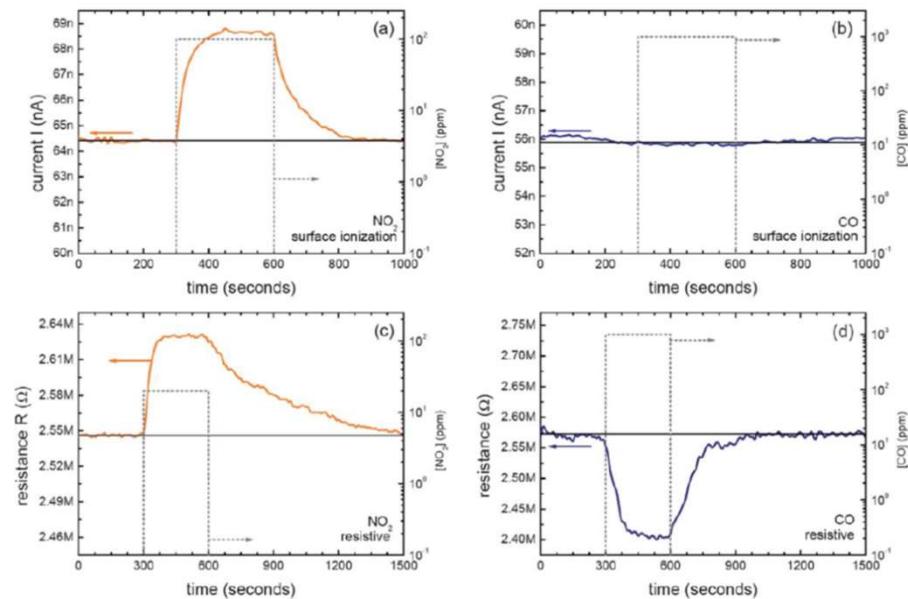
Ionisation Gas Sensor

Adsorbed gas on metal oxide extracted by ionisation applying voltage to a counter electrode

Gap: 400 nm Voltage < 1 V
E-Field > 15 kV/cm



F. Hernandez-Ramirez et al., Nanoscale 3 (2011) 630-634



Sensitivity + Selectivity

Simultaneous ionisation (current) and conductometric (resistance) measurements at very low operating power

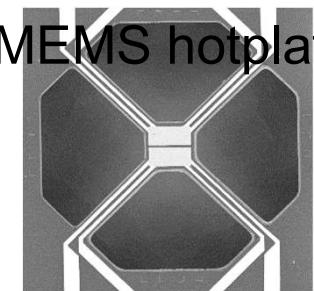


Fabrication of gas sensing nanostructures



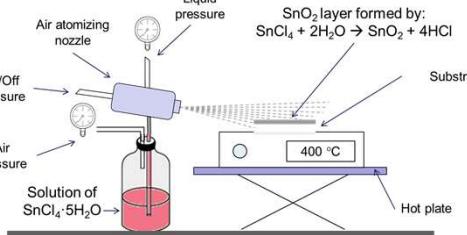
Nanocrystalline Thin Films

MEMS hotplate

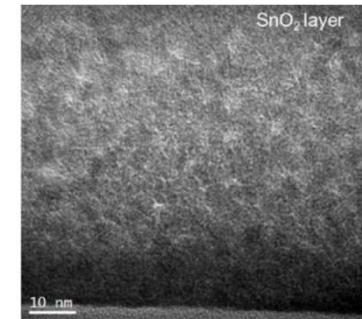


+

Spray Pyrolysis



=

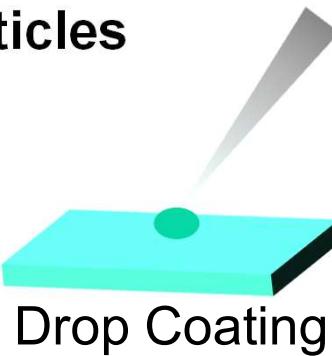


E. Brunet et al., Sens. Act. B 165 (2012) 110-118

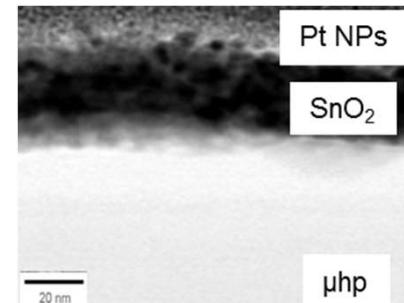
Functionalising Nanoparticles



+



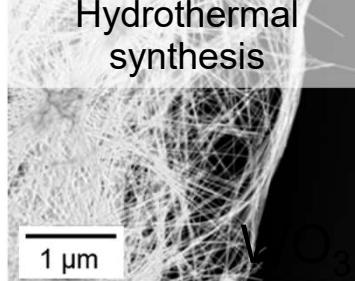
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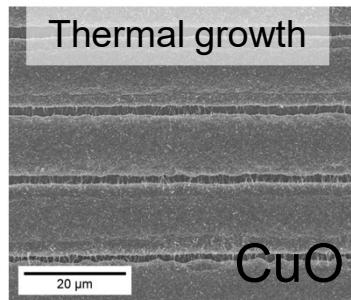
A. Köck, M. Deluca et al., Sensor+Test 2017

Nanowires

Hydrothermal synthesis



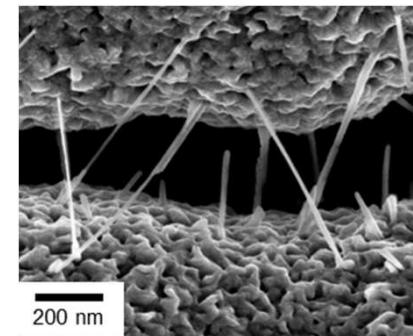
Thermal growth



+

Transfer printing

=



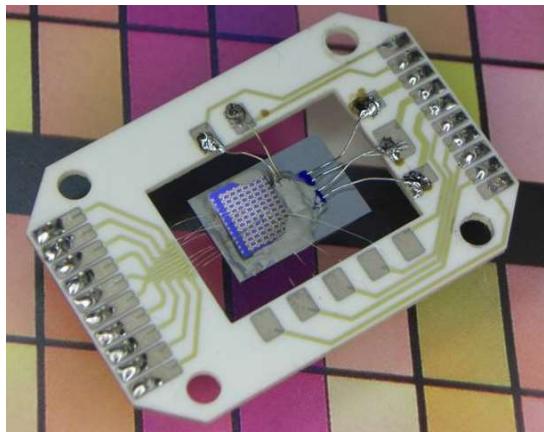
A. Carlson et al., Adv. Mater. 24 (2012) 5284-5318



Low-power gas sensors



Bulk Conductometric



Bulky Pt-heater

Large size ($> 15 \text{ cm}^2$)

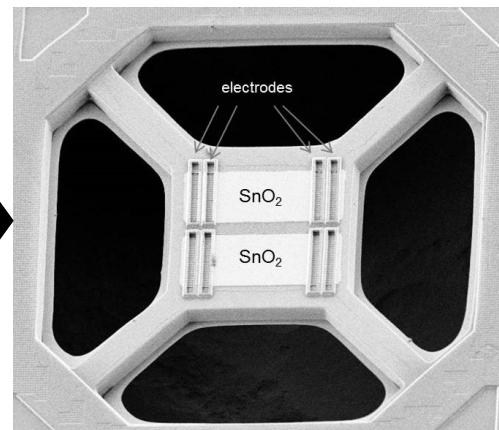
No CMOS-integration

Large power consumption

600 mW operation

4.3 kJ/day

CMOS Conductometric



MEMS polysilicon heater

Small size ($< 5 \text{ mm}^2$)

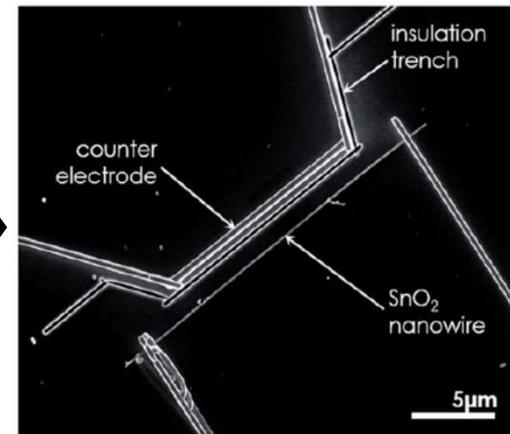
CMOS-integration

Medium power cons.

20 mW operation

144 J/day

Self-heating



Self-heating nanowires

Small size ($< 1 \text{ mm}^2$)

CMOS-integration

Low power consumption

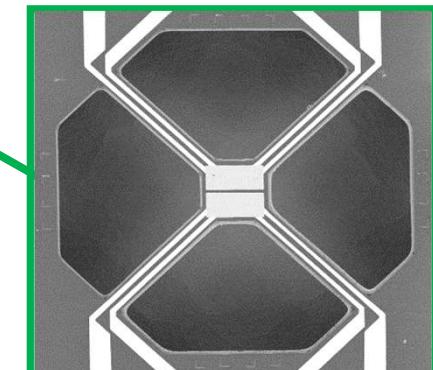
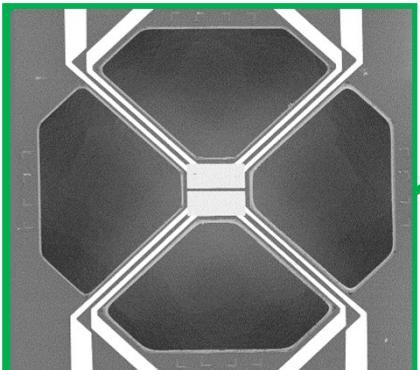
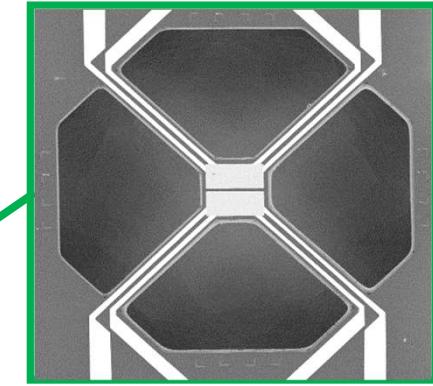
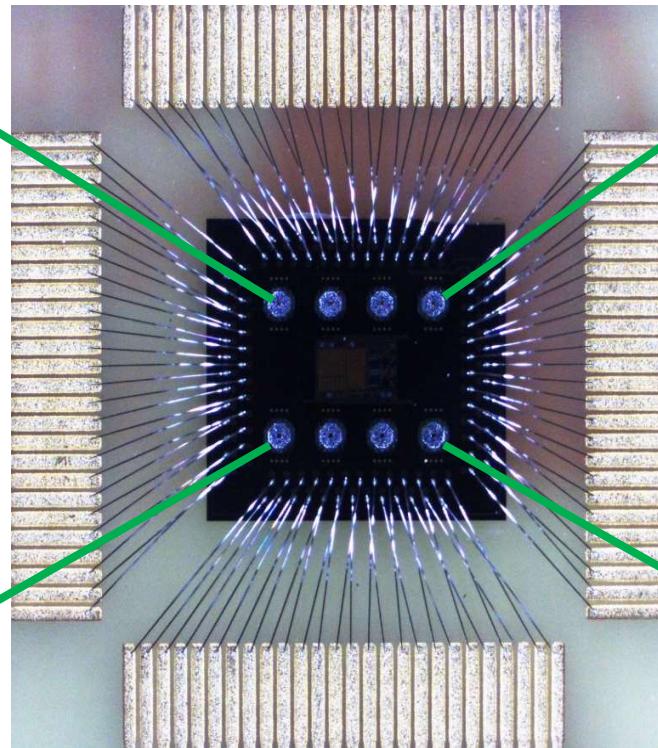
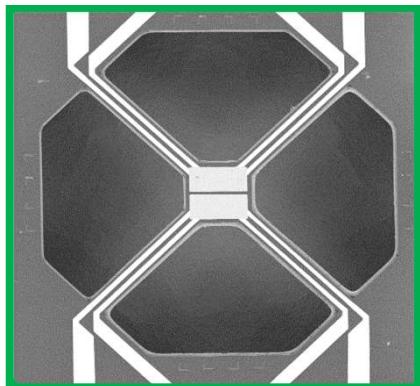
20 μW operation

0.144 J/day

Highly selective gas sensor arrays

MEMS resistive arrays

Self-heating nanowires



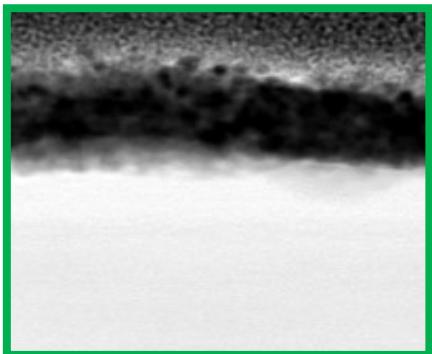
Power consumption: 20 μW

0.144 J/d

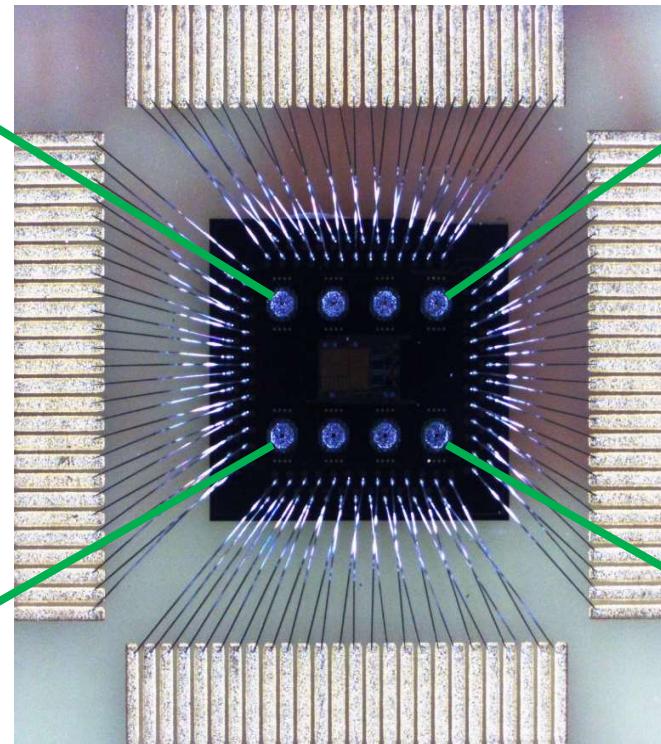
Highly selective gas sensor arrays



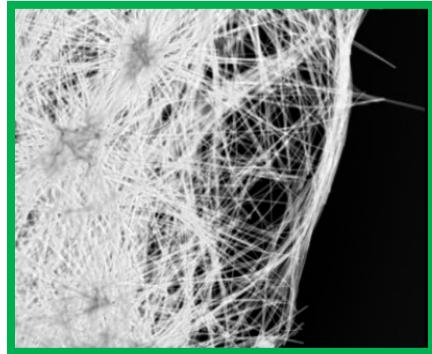
$\text{SnO}_2 + \text{Pt}$



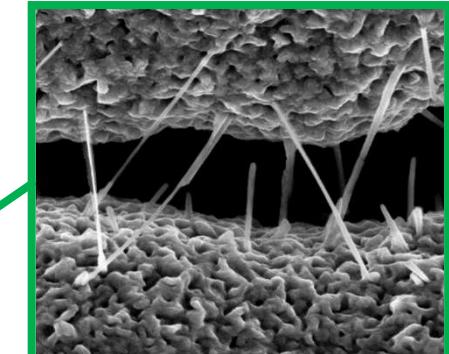
MEMS resistive arrays
Self-heating nanowires



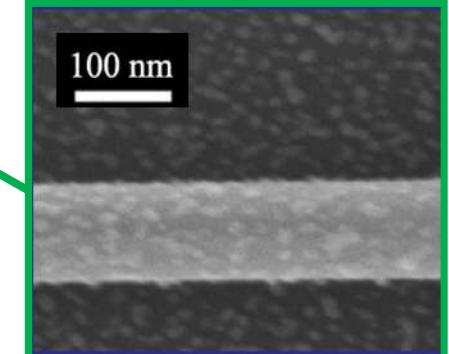
WO_3



CuO-NWs



$\text{CuO-NWs} + \text{Au}$

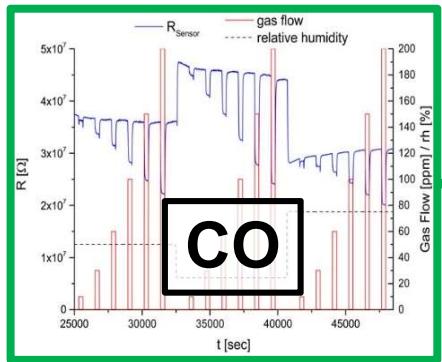


Functionalised with different materials
Selectivity to different gases

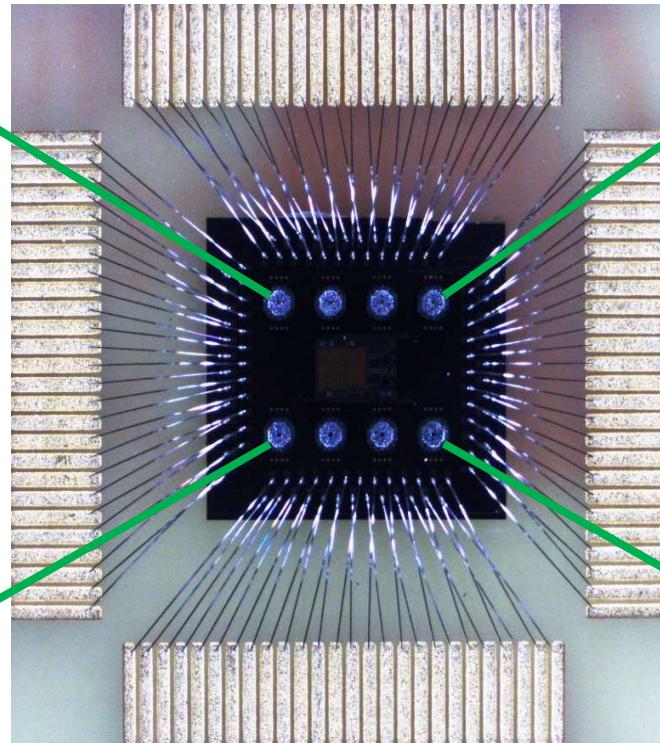
Highly selective gas sensor arrays



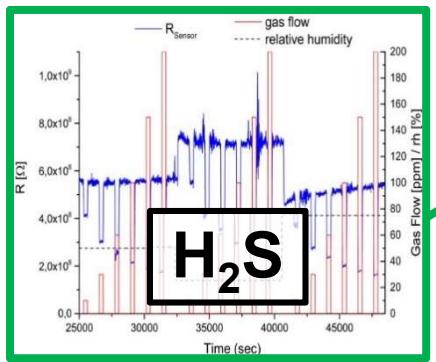
$\text{SnO}_2 + \text{Pt}$



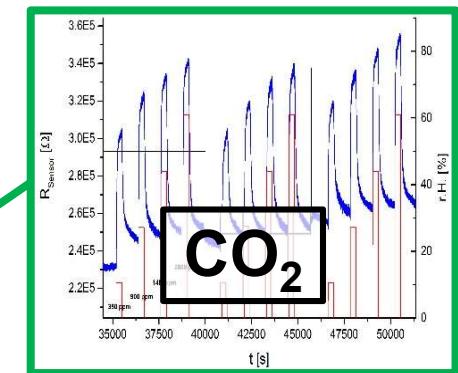
MEMS resistive arrays
Self-heating nanowires



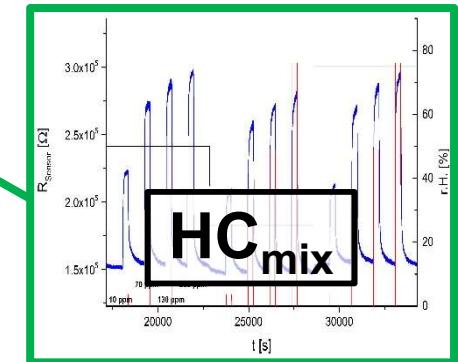
WO_3



CuO-NWs

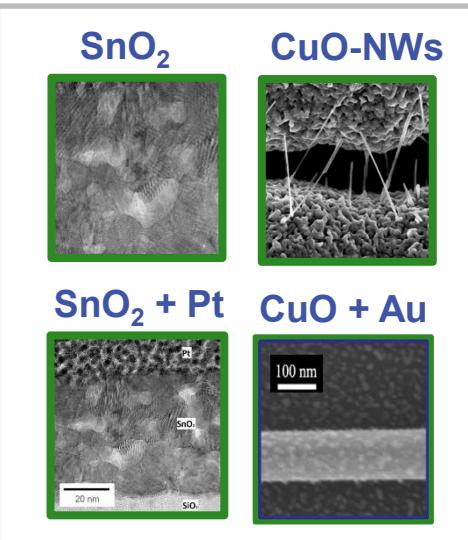


$\text{CuO-NWs} + \text{Au}$

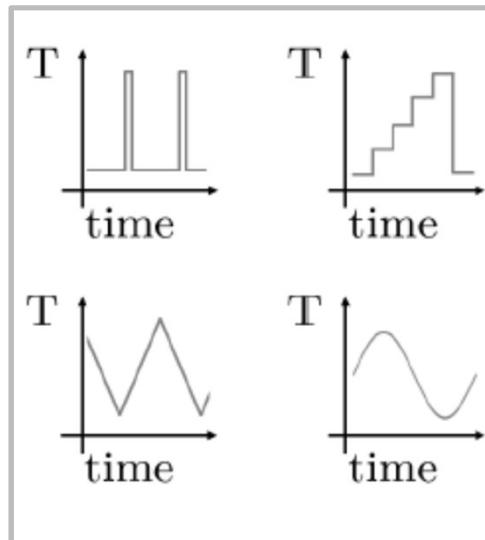


„Cross-Sensitivity“ problem

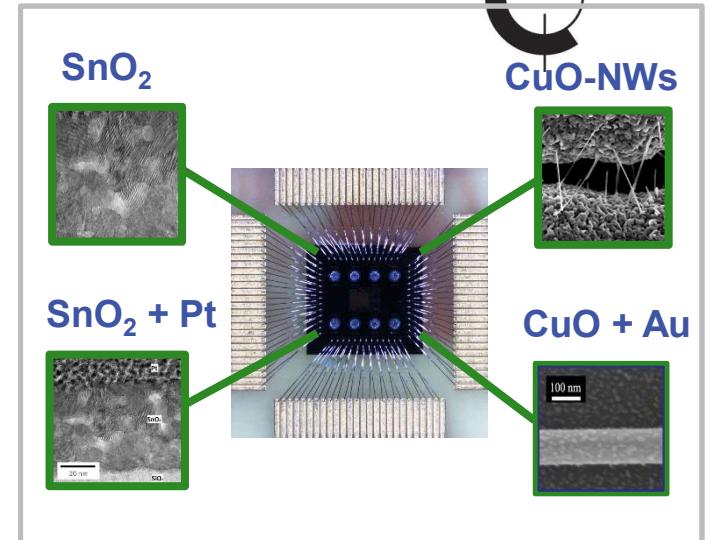
Multifunctional sensors



Single Sensors



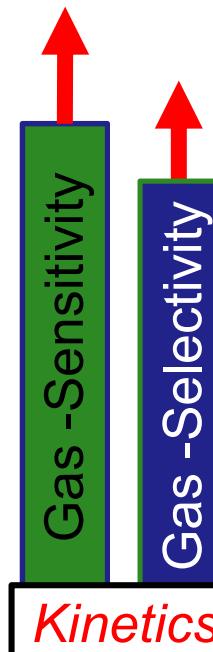
Temperature Cycles



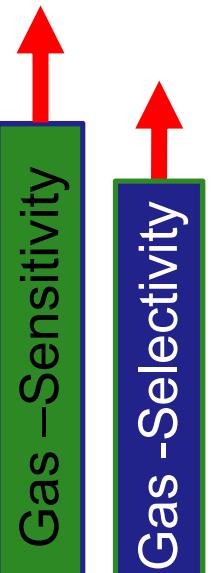
Sensor Arrays



„Steady-State“

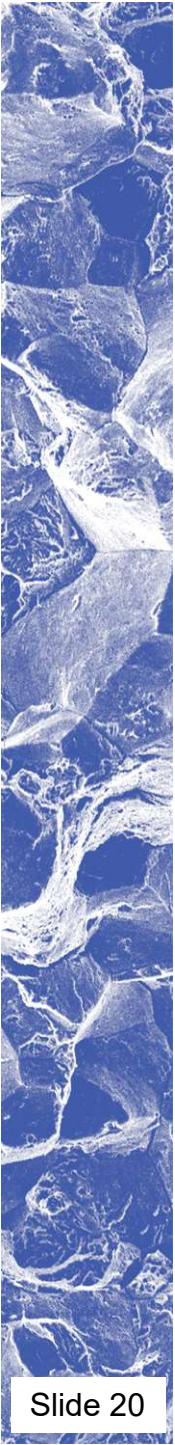


Kinetics

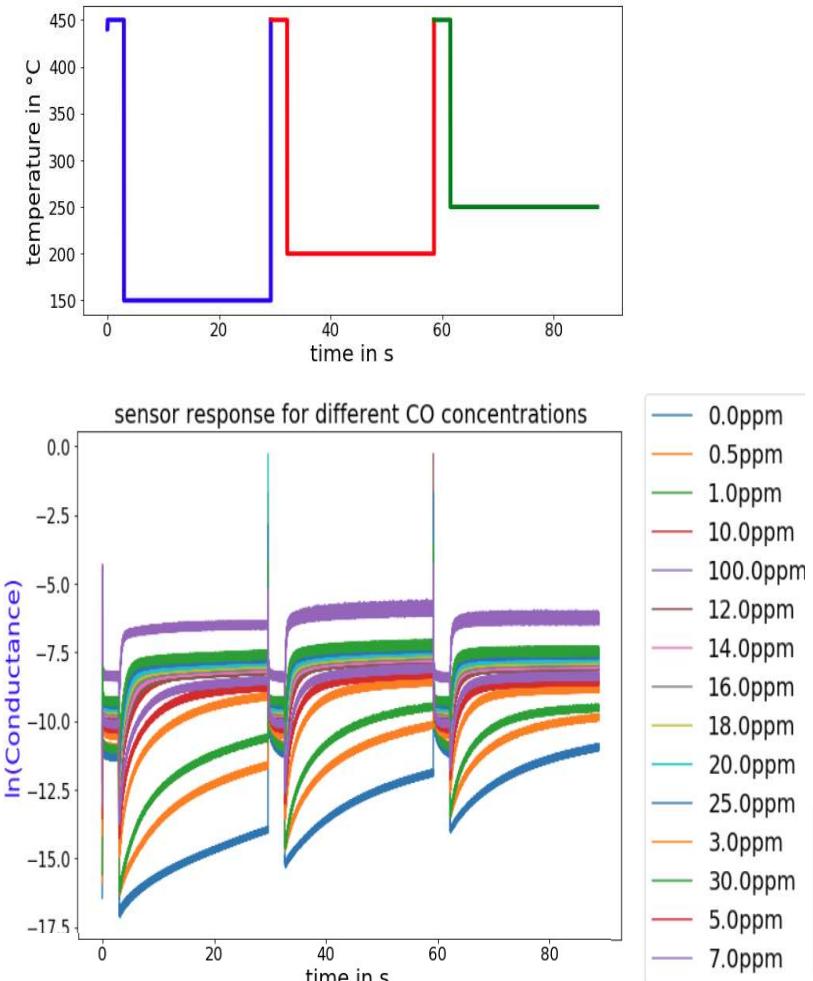


Kinetics + Material

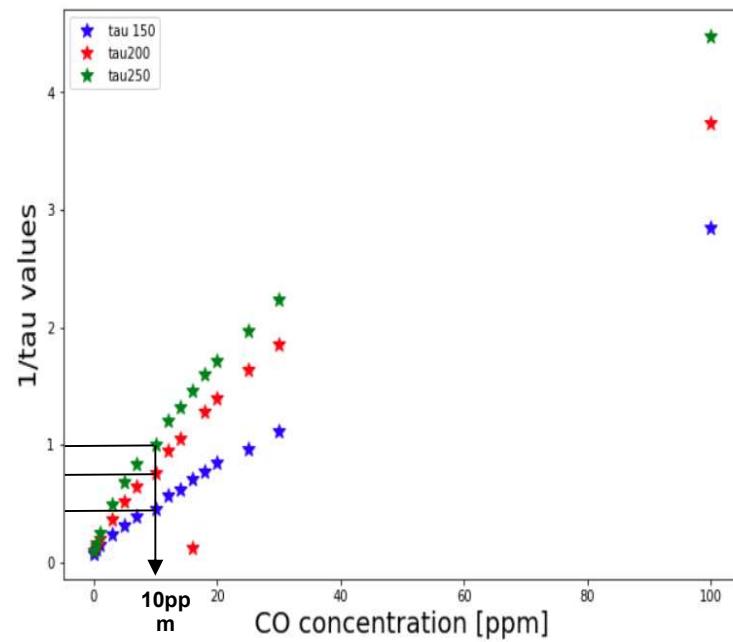
Multifunctional sensors



Temperature cycles for gas quantification



τ -Evaluation for
gas quantification



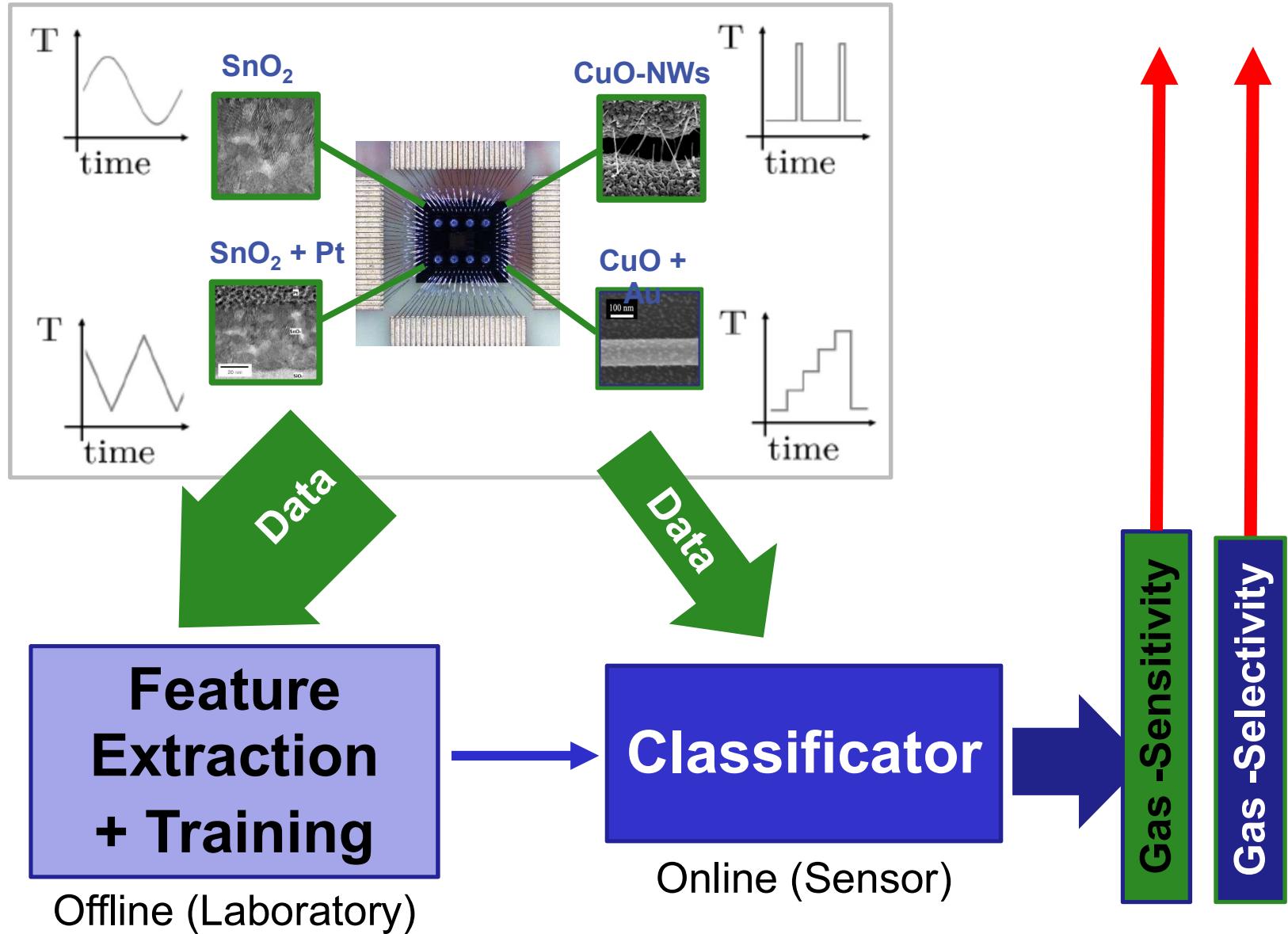
$$\tau = t(0.632(\ln(G_{max}) - \ln(G_{min}))) - t_{start}$$

Kinetics: Slope change is dependent on gas concentration and temperature

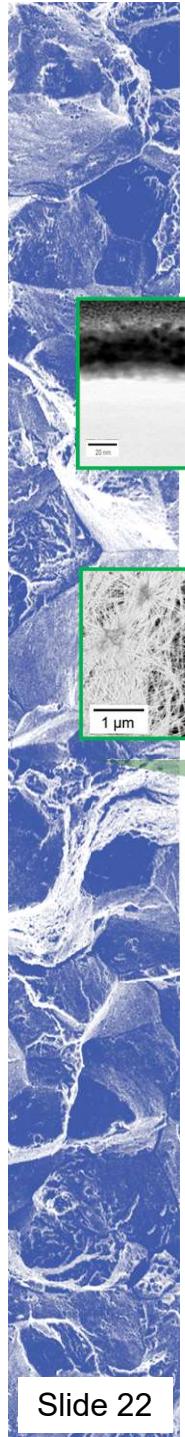
**Faster
measurement!**

Multifunctional sensors

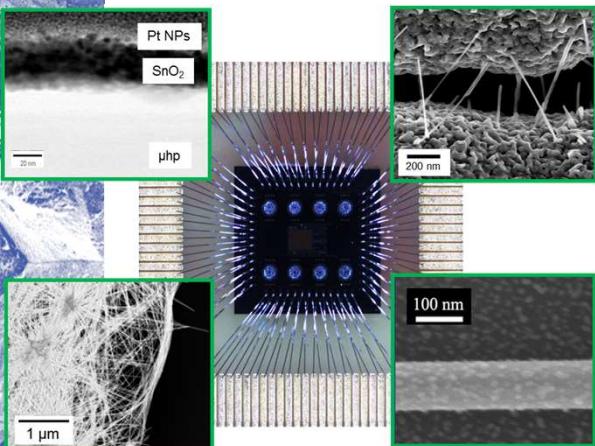
Sensor arrays + Temperature cycles



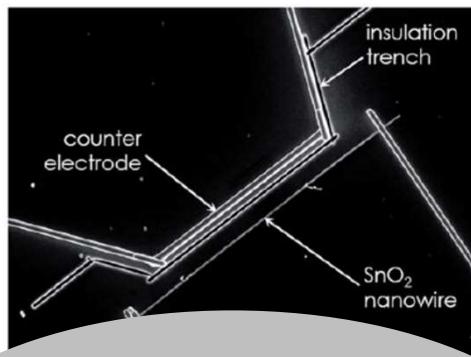
Highly selective gas sensor arrays



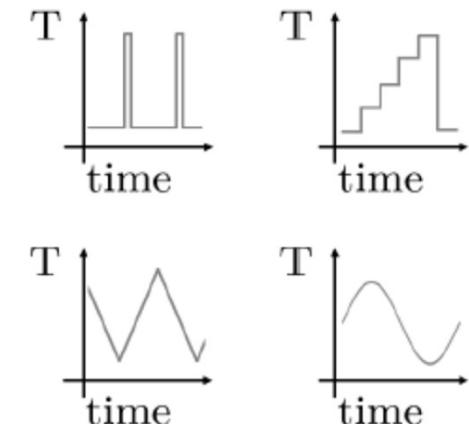
MEMS arrays



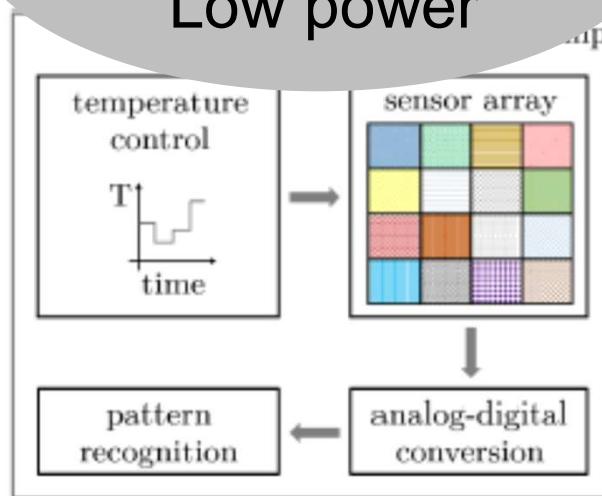
Ionisation sensor



Thermal profiles



High sensitivity
High selectivity
Low power



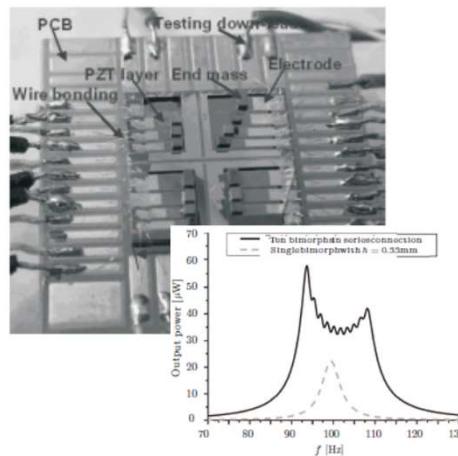
System-on-Chip
for gas detection



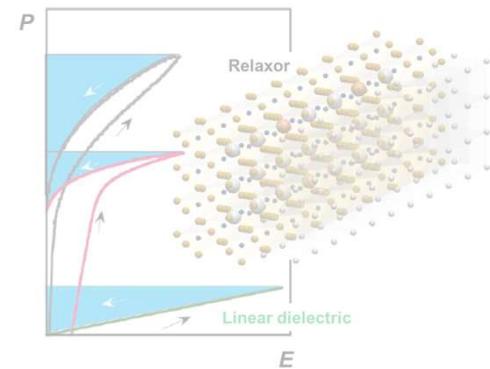
Low-power gas sensors



Broadband piezo-harvesters



High energy-density capacitors

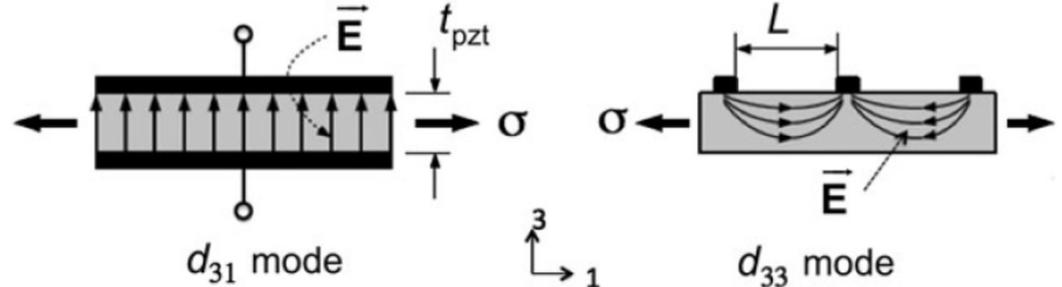
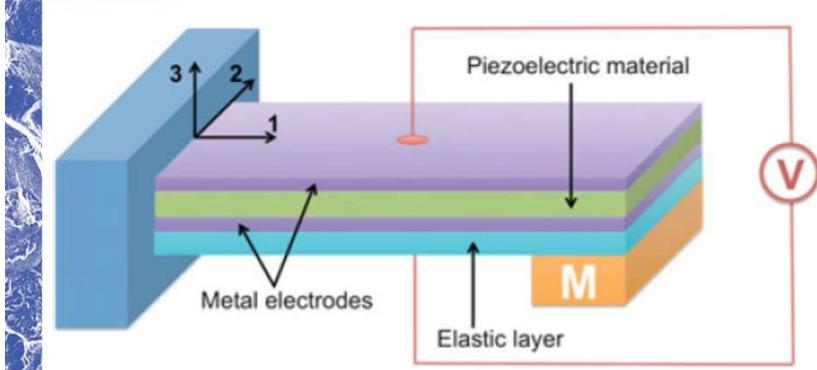




Piezoelectric energy harvesting



Linear piezoelectric energy harvesting



Mode of operation

S.-G. Kim et al., MRS Bull. 37 (2012) 1039-1050

Harvested energy

$$FOM = f \left(\frac{d_{ij}^2 E}{\varepsilon_{33} \sigma \tan \delta} \right)$$

↑ d_{ij} ↑
↓ ε_{33} ↓ E (Young's modulus)
 $\tan \delta$ (mech. losses – $1/Q_m$)



Material	d_{31} (pC/N)	ε_{33}	Frequency (Hz)	Power (μ W/mm ³)
PZT	170	3000	126	20.5
KNN	100	900	1036	6.5
AlN	3	9	214	0.2

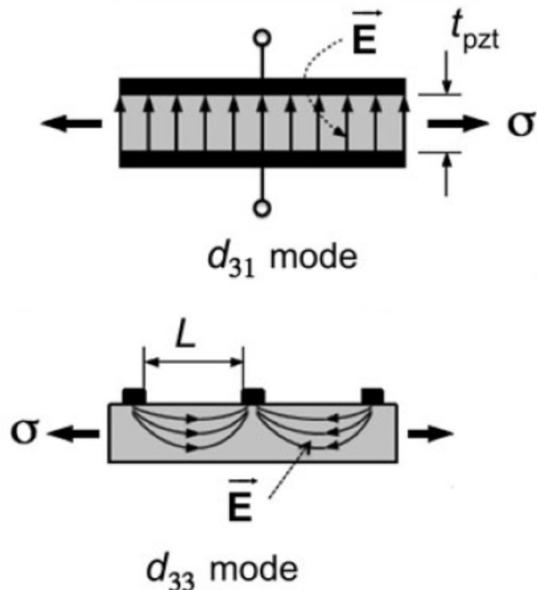
Vibration Source	Frequency (Hz)
Ship engine	12
Numeric control machine	70
Office building, 2 nd floor	100

Main issues

Piezoelectric properties

Maximise d_{ij}

$$FOM = f \left(\frac{d_{ij}^2 E}{\varepsilon_{33}^\sigma \tan \delta} \right)$$



Operational range

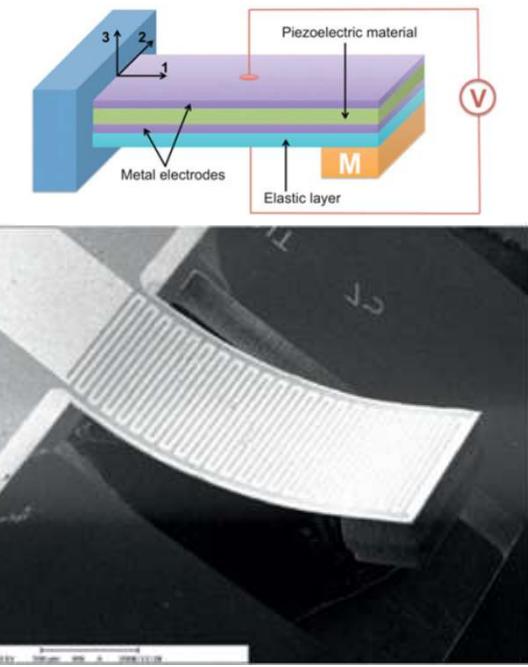
- Frequency matching
- Low-frequency operation
- Broadband operation



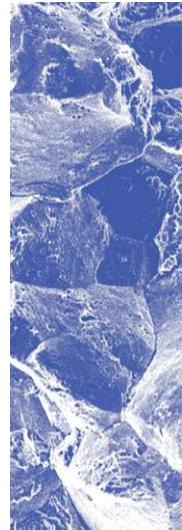
Trade-off ω_r , Q_m

Cost

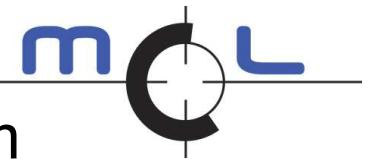
- Thin film deposition
- MEMS structures



S. Priya et al., Energy Harvest. Syst. 4 (2017)



Low-frequency energy harvesting



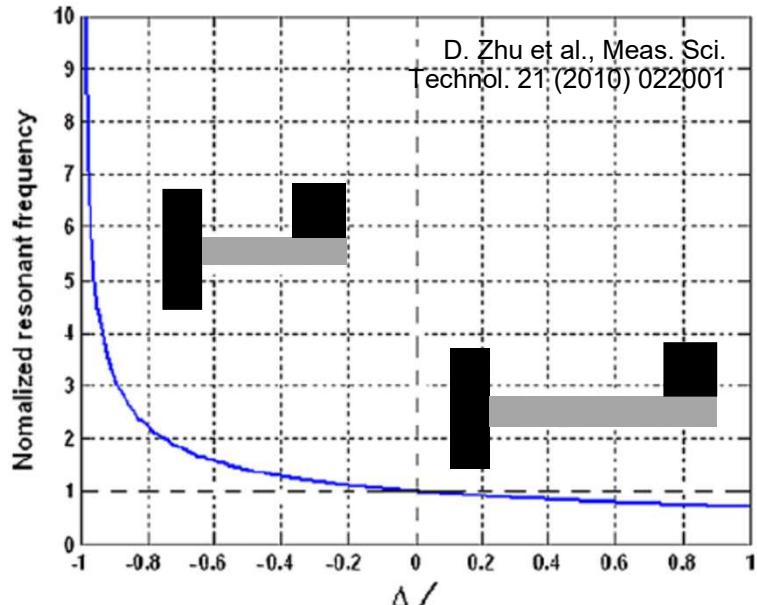
Resonance frequency of mass-cantilever system

$$f_r = \frac{1}{2\pi} \sqrt{\frac{Ewh^3}{4l^3(m + m_c)}}$$

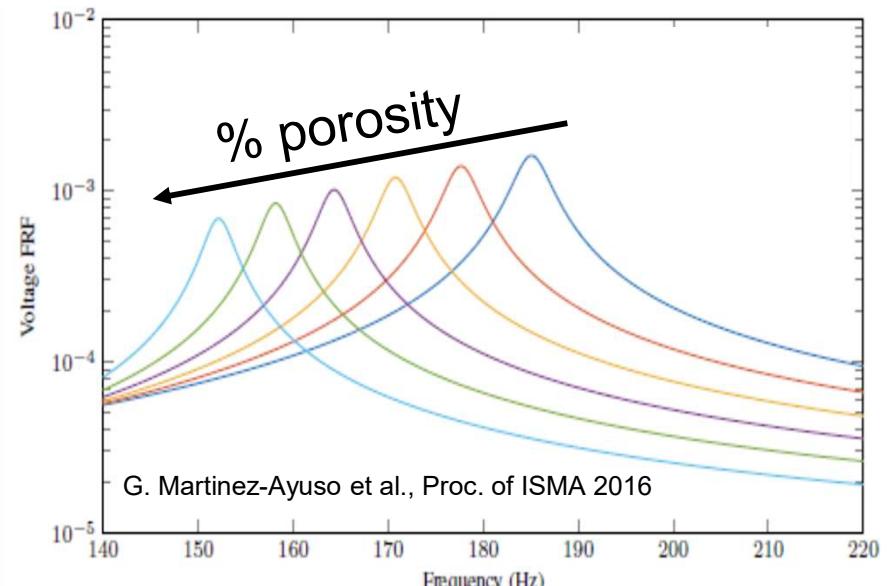
D. Zhu et al., Meas. Sci. Technol. 21 (2010) 022001

w, h, l width, thickness, length of cantilever
 E Young's modulus of cantilever material
 m, m_c mass of proof mass and cantilever

Modify cantilever geometry



Modify Young's modulus

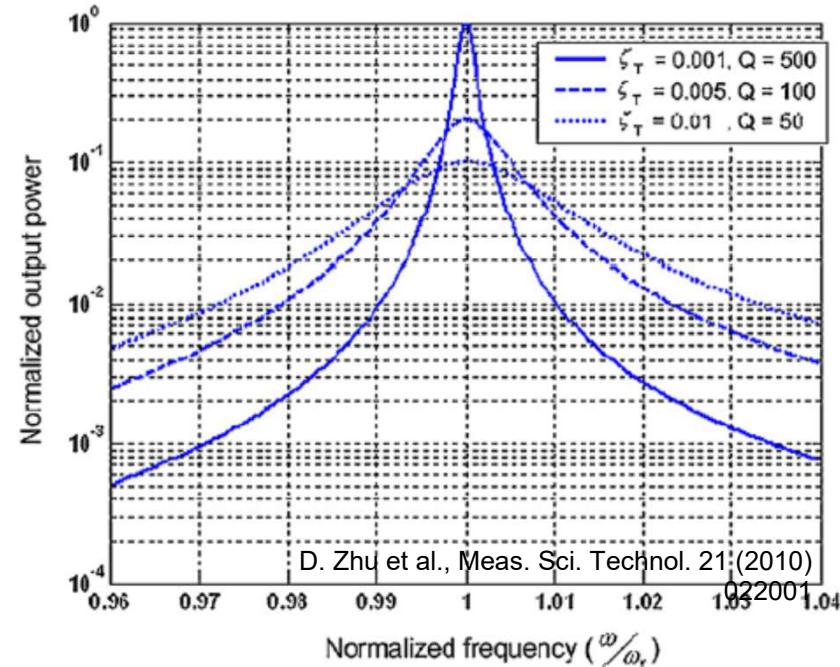




Broadband energy harvesting



Modify Q_m

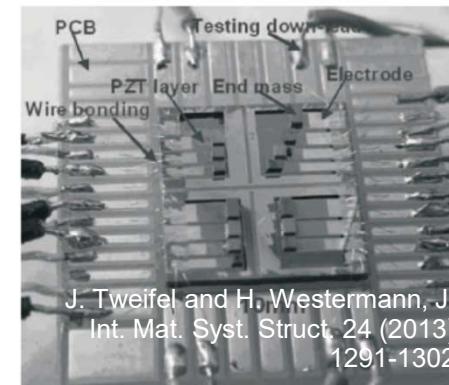


Suitable for low-power applications

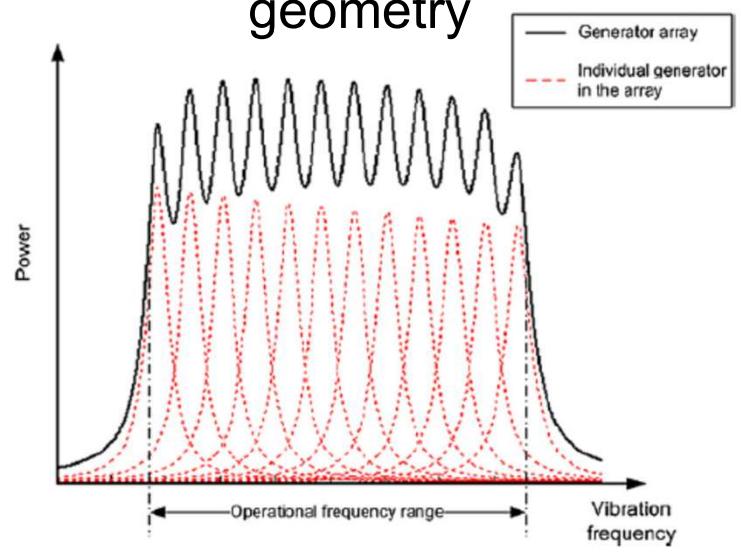
$$\downarrow Q_m = \downarrow \text{Stiffness}$$

- Increase porosity
- Choose „softer“ material (polymer)

Modify Geometry



Cantilever array with variable geometry

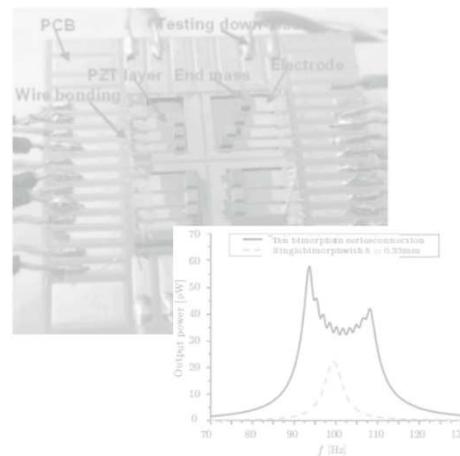




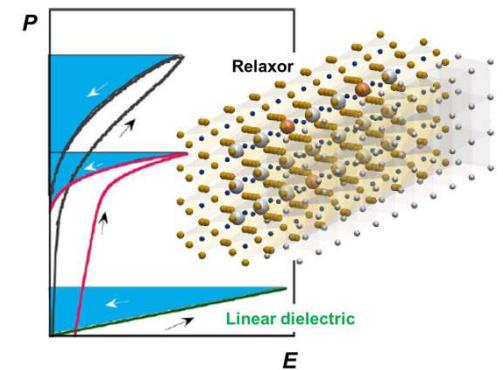
Low-power gas sensors



Broadband piezo-harvesters



High energy-density capacitors





Energy storage for wireless sensors



Energy sources change quickly

Need quick charge/discharge

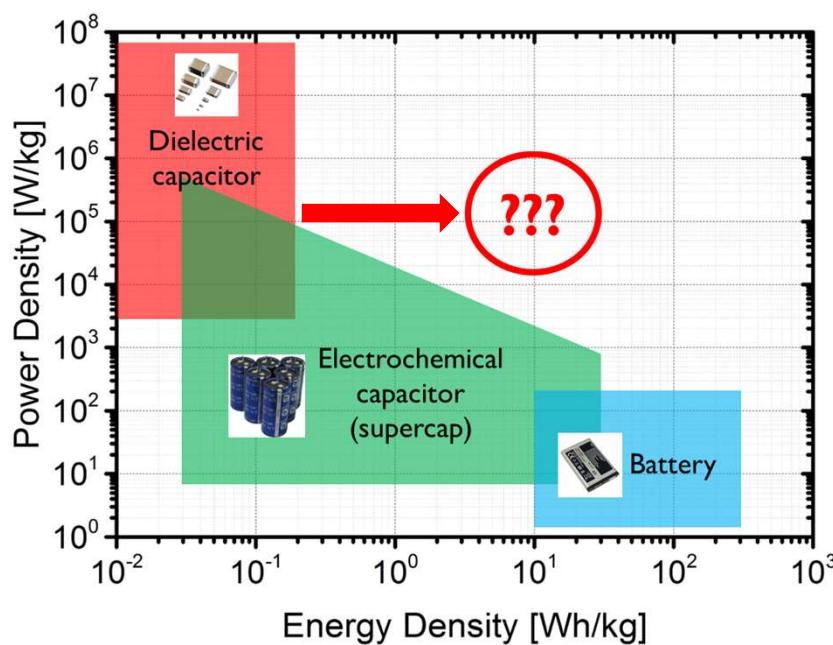
High power density



Energy sources may be not available for long times

Need long-term energy supply

High energy density

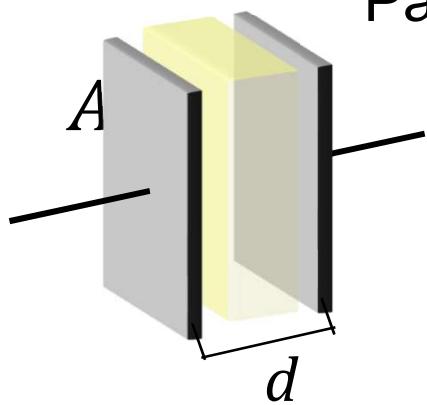


Dielectric capacitors:

- High power density
- Temperature stability
- Cyclic stability

→ **Need high energy density**

Energy density of ceramic capacitors



Parallel plate capacitor with dielectric

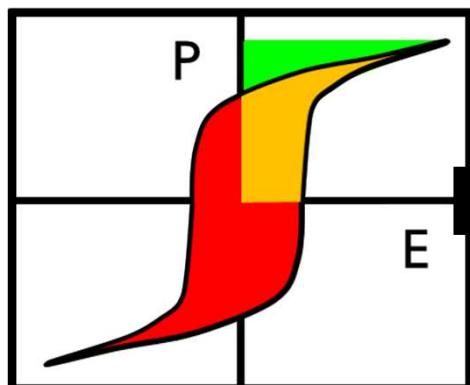
$$U = \frac{1}{2} CV^2 \quad \text{El. potential energy}$$

$$J = \frac{U}{Ad} \quad \text{Energy density}$$

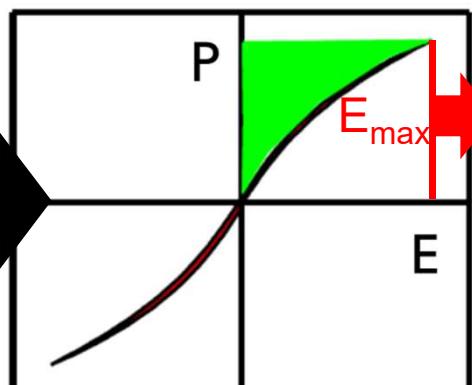
$$J = \frac{1}{2} \varepsilon_0 \varepsilon_r E^2 = \int_{P_1}^{P_2} EdP$$

$$\begin{aligned} C &= \varepsilon_0 \varepsilon_r \frac{A}{d} \\ P &= \varepsilon_0 \varepsilon_r E \end{aligned}$$

Ferroelectric



Relaxor



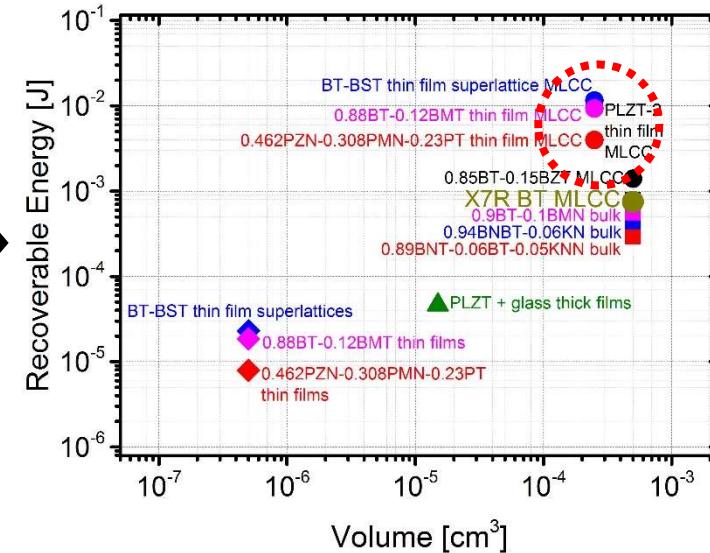
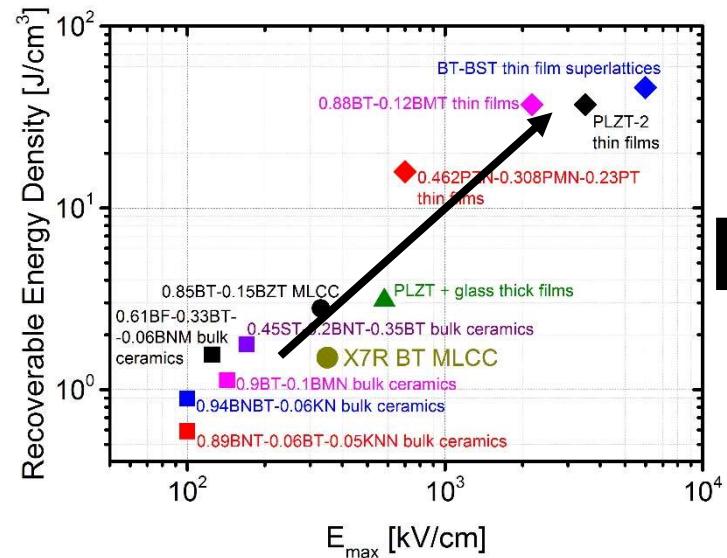
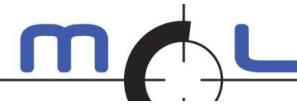
- █ + █ = Stored energy density
- █ = Recoverable energy density
- █ = Energy loss (hysteresis)

Ways to increase energy density:

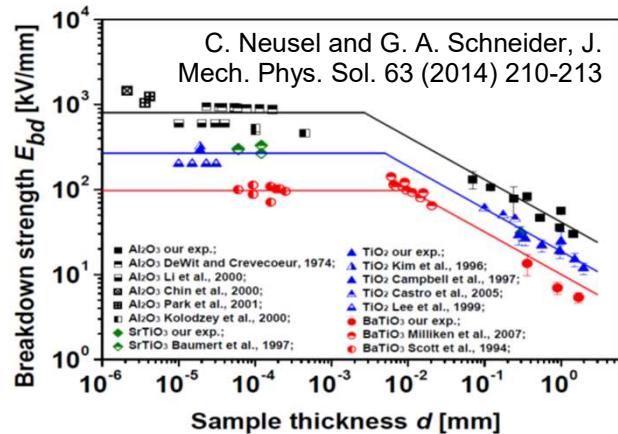
1. Reducing hysteretic losses *while maintaining high permittivity (i.e. P)*
2. Increasing dielectric breakdown strength (DBS) – enhancing E_{max}



Increasing the DBS: Thin film processing

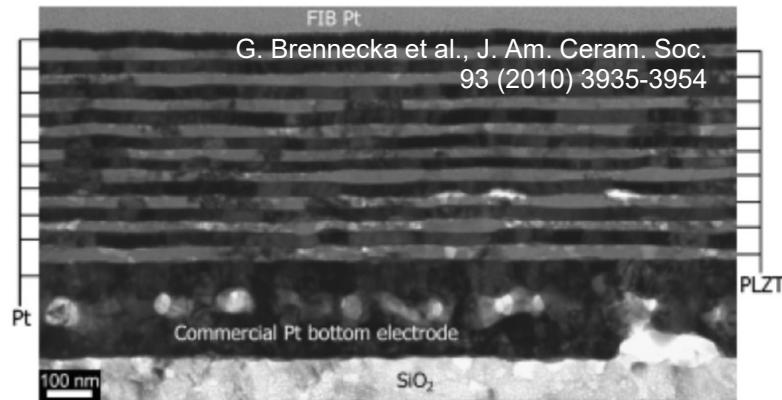


Reduced layer thickness



Less probability to find a critical defect

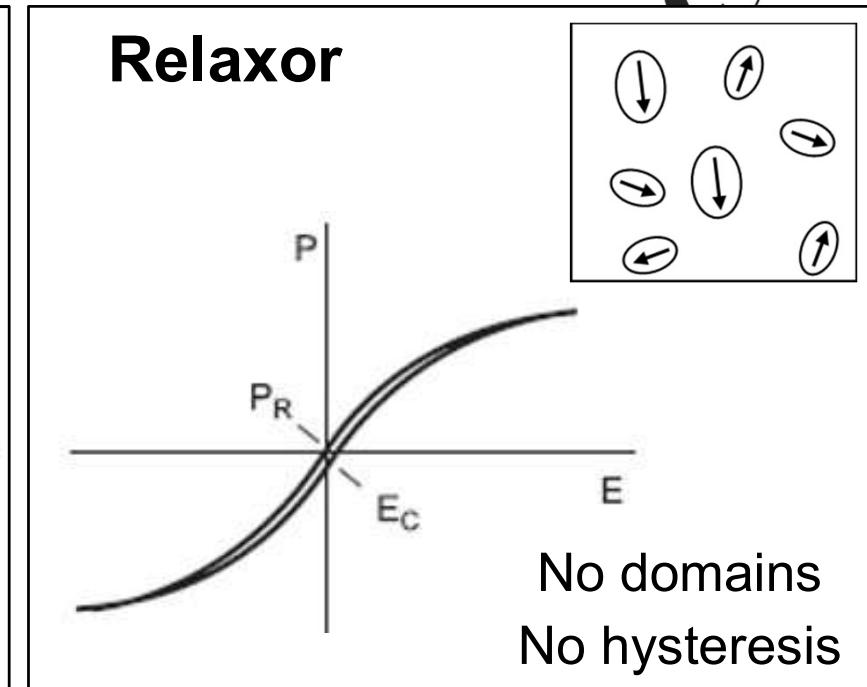
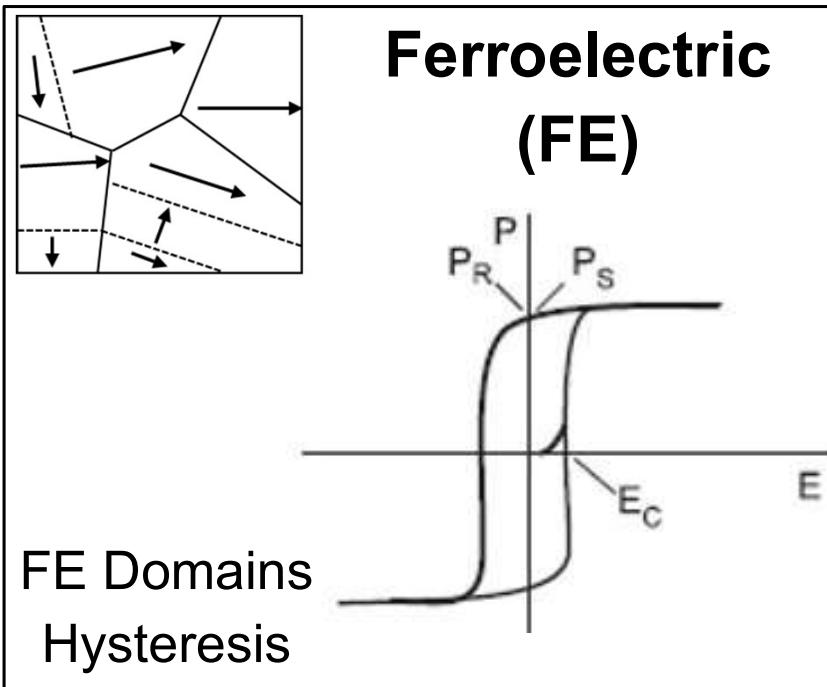
Chemical solution deposition



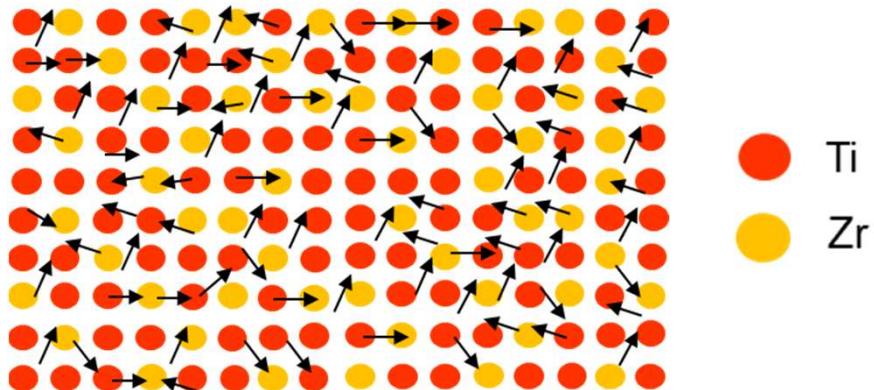
Low porosity and defect density compared to solid-state processing



Optimising the polarisation: Relaxors



$\text{BaZr}_x\text{Ti}_{1-x}\text{O}_3$ (Zr^{4+})
relaxor for $x = 0.35$



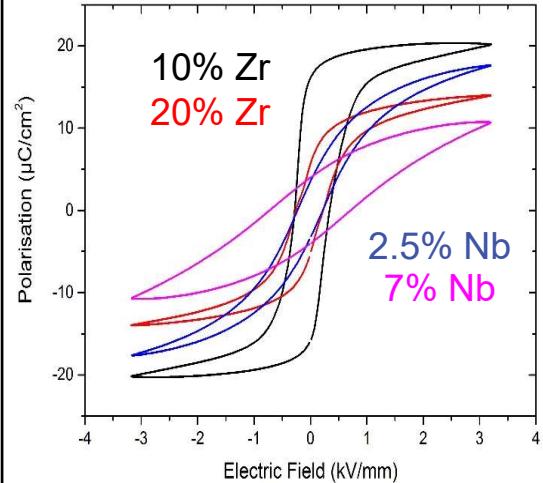
Relaxors: Chemical substitution breaks the long-range cooperative displacement of Ti cations and disrupts ferroelectricity



Optimising the polarisation: Relaxors



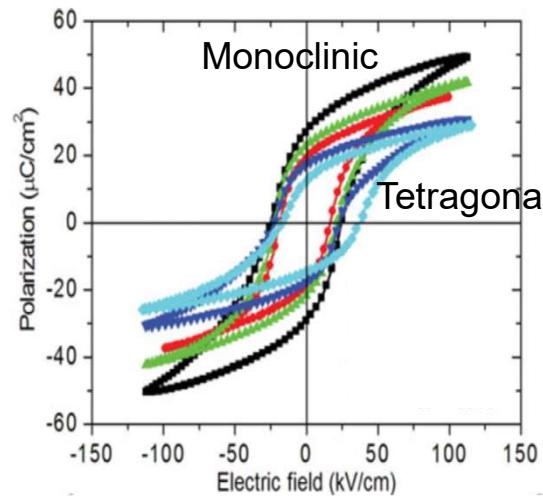
Composition



Substitution disrupts ferroelectricity

M. Deluca et al., unpublished (2019)

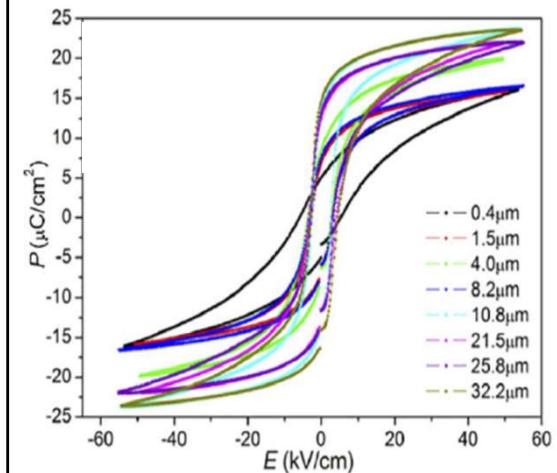
Symmetry



Monoclinic phase increases permittivity

E. C. Lima et al., Ferroel. 465 (2014)

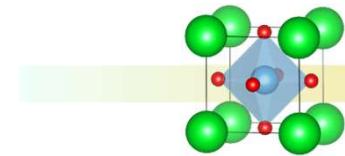
Grain size



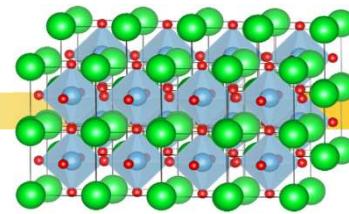
Small grain size suppresses ferroelectricity

M. Acosta et al., Appl. Phys. Rev. 4 (2017) 041305

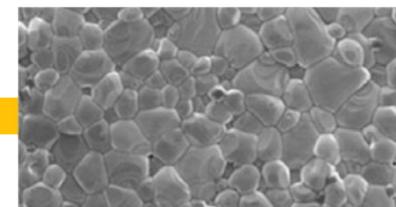
Atomic scale



Nanoscale



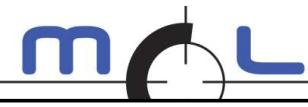
Mesoscale



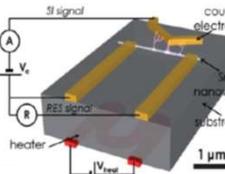
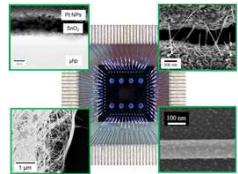
Knowledge of relationship between chemical substitution and macroscopic polarisation is decisive for **optimising polarisation loops** in relaxors.



Self-powered wireless sensor nodes



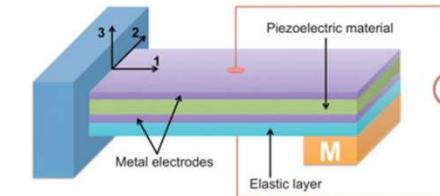
MEMS resistive +
Ionisation gas sensor



0.145 J/day

Sensor

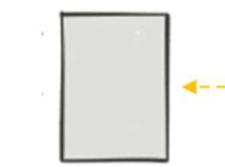
Piezoelectric energy harvester



0.9 J/day

Wireless
module

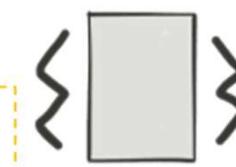
< 0.1 J/day



ASIC

< 0.1 J/day

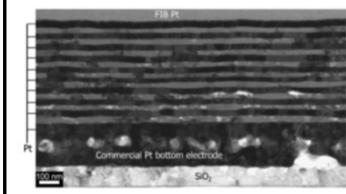
Energy harvester



Energy storage

**Energy autonomous
operation possible!**

Thin film ceramic MLCC



40 J/cm³
8 cycles/hour
0.9 J/day



Take-home messages:

Autonomous IoT sensor nodes must combine the following elements:

- **Low-power sensors** including ASIC and network element
- **Resilient** energy harvesters such as **broadband** and **low-frequency piezoelectric energy harvesters**.
- **High-power** and **high energy density** energy storage.

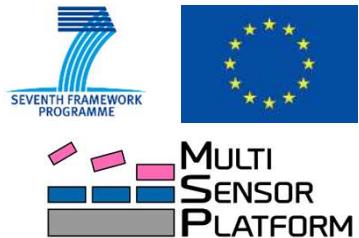
Ionization or **self-heating gas sensors** may be a viable way to reduce power consumption and to improve selectivity.

Piezoelectric energy harvesting is suitable to low-power sensor nodes and works 24/7, but need broadband technology

High storage energy density is attained in **dielectric capacitors** using **thin film** technology and **relaxor systems**



Acknowledgements



FP7-ICT-2013-10 – GA. 611887

MSP – Multi Sensor Platform for Smart Building Management



European Research Council
Established by the European Commission

This project has received funding from the European Research Council (ERC) under the European Union's Horizon 2020 research and innovation programme (grant agreement No 817190)

ERC-COG-2018 – GA. 817190

CITRES - Chemistry and Interface Tailored Relaxor thin films for Energy Storage capacitors



Der Wissenschaftsfonds.

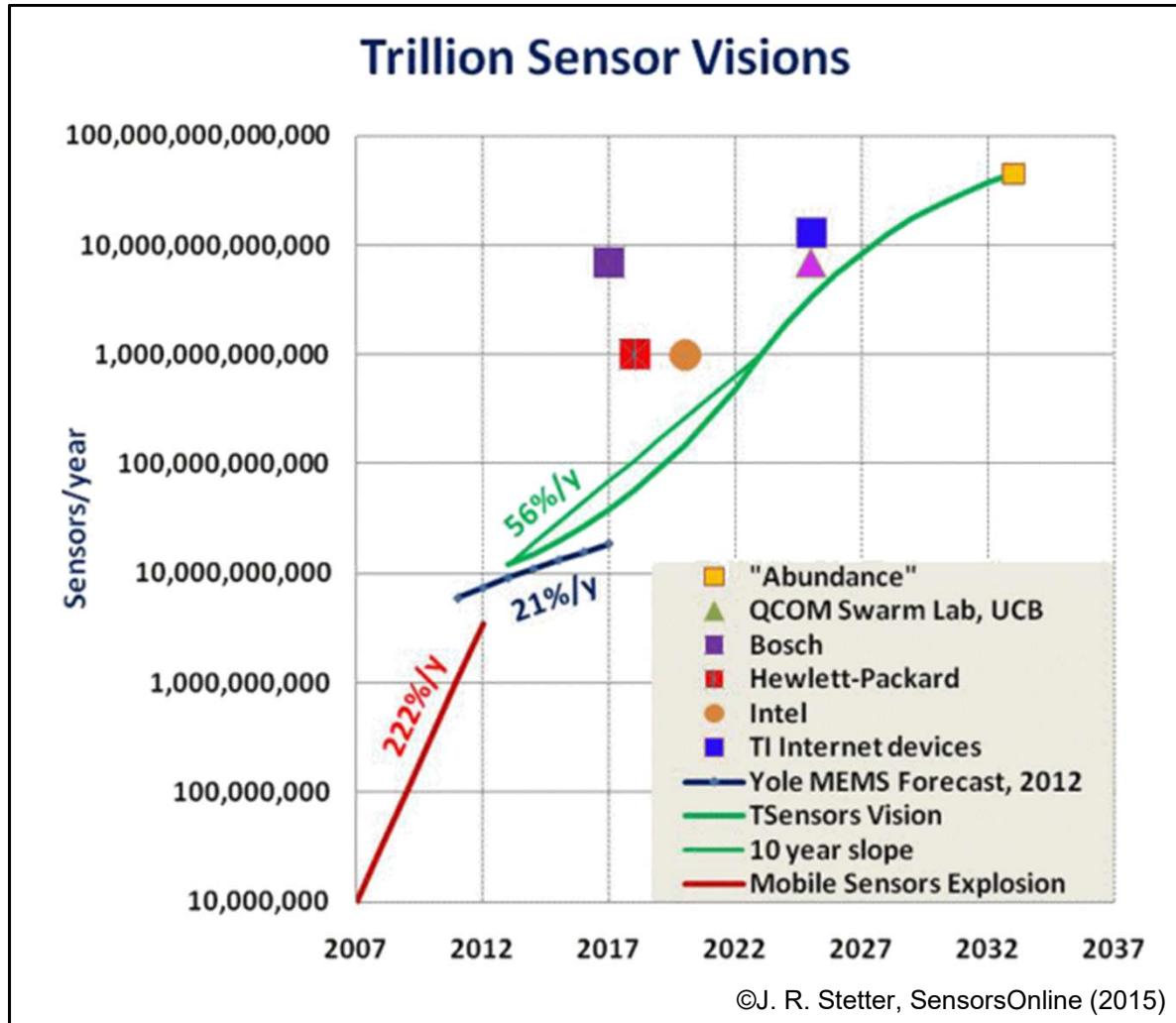
FWF Single Project – Nr. P29563-N36

Origin of relaxor behaviour in Ba-based lead-free perovskites



FFG „Production of the Future“ – Nr. 858637

FUNKYNANO – Optimized Functionalization of Nanosensors for Gas Detection by Screening of Hybrid Nanoparticles



Thank you for your attention!